## **BYC8B-600**

#### **FEATURES**

- Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

## **SYMBOL** k а 3 tab

no connection

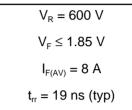
cathode1

anode

cathode

DESCRIPTION

### QUICK REFERENCE DATA

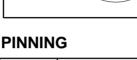


#### **APPLICATIONS**

- Active power factor correction

Half-bridge lighting ballasts
Half-bridge/ full-bridge switched mode power supplies.

The BYC8B-600 is supplied in the SOT404 surface mounting package.



PIN

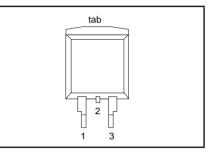
1

2

3

tab

#### **SOT404**



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	Peak repetitive reverse voltage		-	600	V
V <sub>RWM</sub>	Crest working reverse voltage		-	600	V
V <sub>R</sub>	Continuous reverse voltage	T <sub>mb</sub> ≤ 110 °C	-	500	V
I <sub>F(AV)</sub>	Average forward current	$\delta = 0.5$ ; with reapplied V <sub>RRM(max)</sub> ; T <sub>mb</sub> $\leq 82 \degree$ C	-	8	A
I <sub>FRM</sub>	Repetitive peak forward current	$\delta = 0.5$ ; with reapplied V <sub>RRM(max)</sub> ; T <sub>mb</sub> $\leq 82 \degree$ C	-	16	A
I <sub>FSM</sub>	Non-repetitive peak forward	t = 10 ms	-	55	Α
	current.	t = 8.3 ms	-	60	Α
		sinusoidal; $T_j = 150^{\circ}C$ prior to surge with reapplied $V_{RWM(max)}$			
T <sub>stg</sub>	Storage temperature		-40	150	°C
T <sub>j</sub>	Operating junction temperature		-	150	°C

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance junction to		-	-	2.2	K/W
R <sub>th j-a</sub>	mounting base Thermal resistance junction to ambient	minimum footprint, FR4 board	-	50	-	K/W

<sup>1</sup> it is not possible to make connection to pin 2 of the SOT404 package

## **BYC8B-600**

#### **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 8 A; T <sub>i</sub> = 150°C I <sub>F</sub> = 16 A; T <sub>i</sub> = 150°C	-	1.4 1.7	1.85 2.3	V V
I <sub>R</sub>	Reverse current	I <sub>F</sub> = 8 A; V <sub>R</sub> = 600 V V <sub>R</sub> = 500 V; T <sub>j</sub> = 100 °C	- - -	2.0 9 1.1	2.8 150 3.0	ν μΑ mA
t <sub>rr</sub> t <sub>rr</sub>	Reverse recovery time Reverse recovery time	$I_{F} = 1 \text{ A}; V_{R} = 30 \text{ V}; dI_{F}/dt = 50 \text{ A}/\mu\text{s}$ $I_{F} = 8 \text{ A}; V_{R} = 400 \text{ V};$ $dI_{F}/dt = 500 \text{ A}/\mu\text{s}$ $I_{F} = 8 \text{ A}; V_{R} = 400 \text{ V};$	-	30 19 32	52 - 40	ns ns
t <sub>rr</sub>	Reverse recovery time	dl <sub>F</sub> /dt = 500 A/μs; T <sub>j</sub> = 125°C	-			ns
I <sub>rrm</sub>	Peak reverse recovery current	I <sub>F</sub> = 8 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 50 A/μs; T <sub>i</sub> = 125°C	-	1.5	5.5	A
Irrm	Peak reverse recovery current	I <sub>F</sub> = 8 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 500 A/μs; T <sub>j</sub> = 125°C	-	9.5	12	A
V <sub>fr</sub>	Forward recovery voltage	$I_F = 10 \text{ A}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	8	10	V

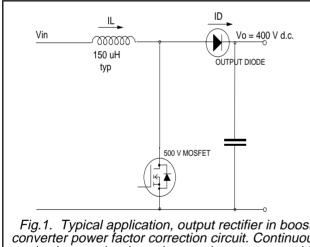
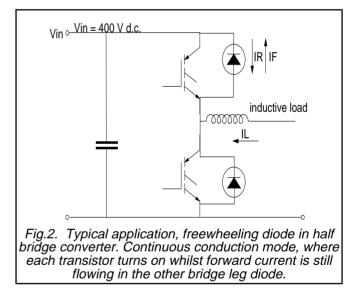
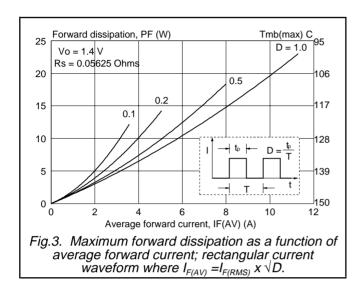


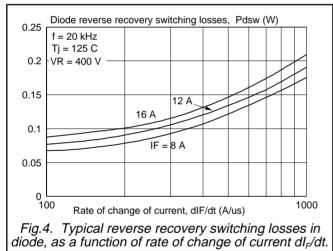
Fig.1. Typical application, output rectifier in boost converter power factor correction circuit. Continuous conduction, mode where the transistor turns on whilst forward current is still flowing in the diode.

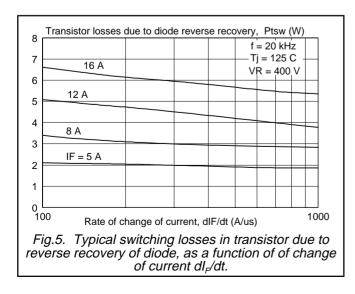


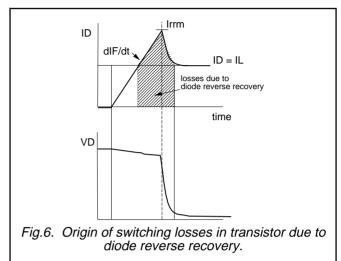
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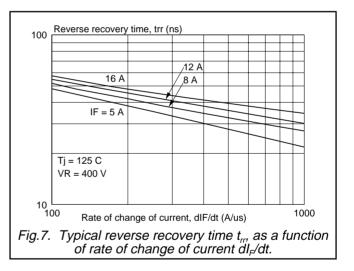
#### Rectifier diode ultrafast, low switching loss

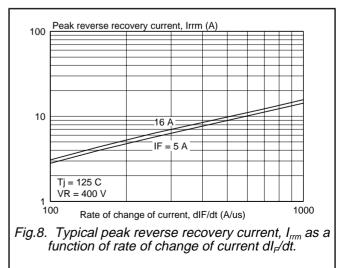


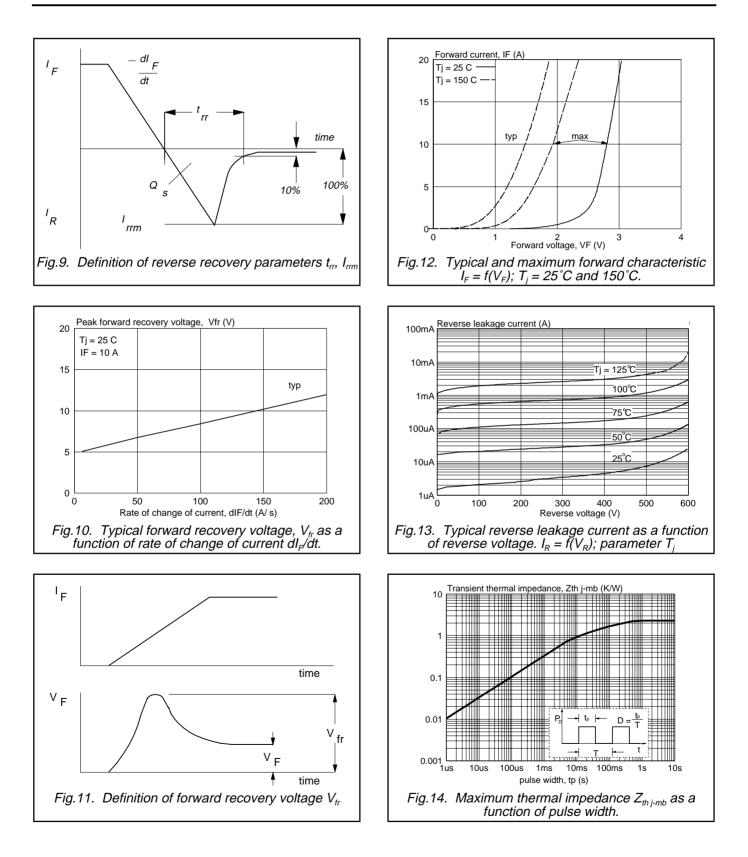








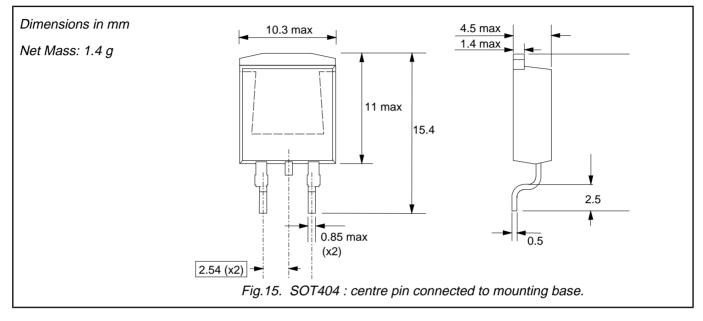




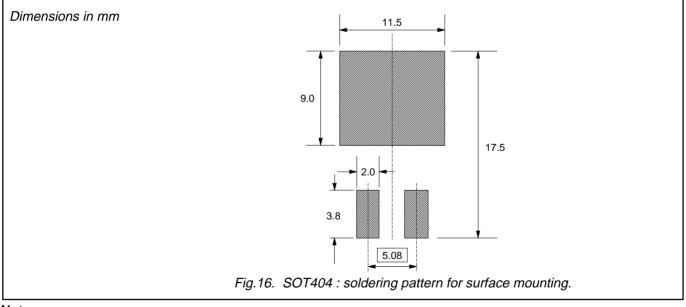
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#### **MECHANICAL DATA**



#### **MOUNTING INSTRUCTIONS**



#### Notes

1. Epoxy meets UL94 V0 at 1/8".

## BYC8B-600

#### DEFINITIONS

Data sheet status			
Objective specification	tive specification This data sheet contains target or goal specifications for product development.		
Preliminary specification	cation This data sheet contains preliminary data; supplementary data may be published later.		
Product specification	This data sheet contains final product specifications.		
Limiting values			
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.			
Application information			
Where application information is given, it is advisory and does not form part of the specification.			
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